## NSN 5961-01-104-8554

Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-104-8554 **Inclosure Material:** Metal **Overall Length:** 0.805 inches **Overall Height:** 0.175 inches **Overall Width:** 0.265 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 45.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 bracket and 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No